

isc N-Channel MOSFET Transistor

AOT12N30

FEATURES

- Drain Current –I_D= 11.5A@ T_C=25 $^\circ\!\!\mathrm{C}$
- Drain Source Voltage-: V_{DSS}= 300V(Min)
- Static Drain-Source On-Resistance
- : R_{DS(on)} = 0.42 Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

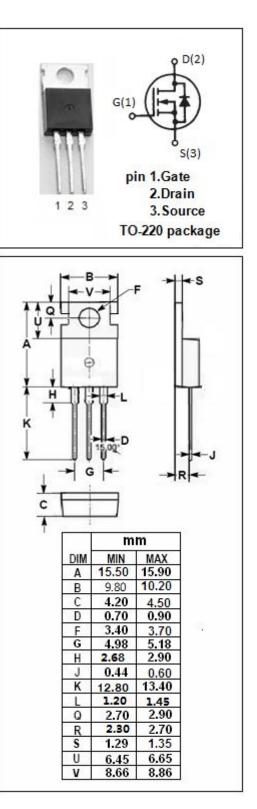
• Designed for use in switch mode power supplies and general purpose applications.

SYMBOL	PARAMETER	VALUE	UNIT				
V _{DSS}	Orain-Source Voltage 300		V				
V _{GS}	Gate-Source Voltage-Continuous	±30	V				
ID	Drain Current-Continuous 11.5		А				
I _{DM}	Drain Current-Single Pluse 29		A				
P _D	Total Dissipation @T _c =25℃	al Dissipation @T _c =25°C 132					
TJ	Max. Operating Junction Temperature	-55~150	°C				
T _{stg}	Storage Temperature	-55~150	°C				

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.95	°C/W



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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	300			V
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} = 5V; I _D = 0.25mA	3.4		4.5	V
$R_{DS(on)}$	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 6A			0.42	Ω
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±30V;V _{DS} = 0			±100	nA
IDSS	Zero Gate Voltage Drain Current	V _{DS} = 300V; V _{GS} = 0 V _{DS} = 240V; V _{GS} = 0@T _J =125°C			1 10	μA
V_{SD}	Forward On-Voltage	I _S = 1A; V _{GS} = 0			1	v



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